	Hits	Search Text	DBs	Time Stamp
1	31741	pixel adj (electrode electrodes)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 12:01
2	8016	pixel adj (electrode electrodes) with light	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/08/07 20:35
3	292	_	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/19 13:58
4	11	electrodes) with light same	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 12:01
5	78453	Thin adj film adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM TDB	2006/02/04 14:12
6	2859	(thin adj film adj transistor	1H: P() + 11 P() +	2006/02/04 14:36
7	427	(thin adj film adj transistor TFT) and gate adj wiring and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:13
8	20	obmic add contact and auxiliary	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:37
9	6	TFT) and gate adj line and gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:22

	Hits	Search Text	DBs	Time Stamp
10	2	(thin adj film adj transistor TFT) and gate adj wiring and ohmic adj contact and auxiliary adj gate and gate adj end	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:37
11	8	(thin adj film adj transistor TFT) and gate adj wiring and ohmic adj contact and auxiliary adj gate not samsung	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:25
12	8	(thin adj film adj transistor TFT) and gate adj wiring and ohmic adj contact and gate adj end	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:34
13	75068	(thin adj film adj transistor TFT) not samsung	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:37
14		(thin adj film adj transistor TFT) and gate adj wiring and ohmic adj contact and auxiliary	EPO; JPO;	2006/02/04 14:37
15	3	obmic adi contact and auxiliary	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:37
16	i i	<u> </u>	EPO; JPO;	2006/02/04 14:38
17	1087	(thin adj film adj transistor TFT) and ohmic adj contact and gate adj electrodes and	H:P() • .1P() •	2006/02/04 14:39
18	397	TFT) and ohmic adj contact and gate adj electrodes and transparent and data adj line	18: D( ) • . 1 D( ) •	2006/02/04 14:39

	Hits	Search Text	DBs	Time Stamp
19	30	TFT) and ohmic adj contact and gate adj electrodes and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/02/04 14:40
20	2	"20040266039"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/21 13:08
21	902	(liquid adj crystal adj (device	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 11:51
22	445	substrate with inches and (liquid adj crystal adj (device	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 11:52
23	276	(liquid adj crystal adj (device display) LCD) and pixel and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 11:53
24	922	438/30.ccls.	IH: D() • . I D() •	2006/04/03 11:59
25	324	438/152.ccls.	IE: P() + 11 P() +	2006/04/03 11:59
26	1680	438/149.ccls.	IH: D( ) • .   D( ) •	2006/04/03 11:59
27	160	438/161.ccls.	1H: P() + .   P() +	2006/04/03 12:00

	Hits	Search Text	DBs	Time Stamp
28	588	pixel adj (electrode electrodes) and S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/03 12:01
29	43	pixel adj (electrode electrodes) and S26	IH: D( ) • I D( ) •	2006/04/03 12:01
30	634	pixel adj (electrode electrodes) and S27	IH: P( ) • . I P( ) •	2006/04/03 12:01
31	56	pixel adj (electrode electrodes) and S28	IH: P( ) • .   P( ) •	2006/04/03 12:01
32	О	pixel adj (electrode	EPO; JPO;	2006/04/03 12:01
33	0	pixel adj (electrode electrodes) and light same perpendicular same mask and S28	EPO; JPO;	2006/04/03 12:01
34	3	pixel adj (electrode electrodes) and light same perpendicular same mask and S25	EPO; JPO;	2006/04/03 12:02
35	7	pixel adj (electrode electrodes) and light same perpendicular same mask and S27	EPO; JPO;	2006/04/03 12:02
36	2	"20030211404"	H:PO · TPO ·	2006/04/19 13:55

	Hits	Search Text	DBs	Time Stamp
37	3541	light with perpendicular with (mask photomark pattern)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/19 13:58
38	588	light with perpendicular with (mask photomark pattern) and pixel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/19 14:00
39	389	light with perpendicular with (mask photomark pattern) and pixel and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/20 10:52
40	89	light with perpendicular with (mask photomark pattern) and pixel adj (electrode electrodes) and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/20 10:50
41	49	ngcan gcanning gcanneg, ang	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM TDB	2006/04/20 10:53
42	1	(mask photomark pattern) same (scan scanning scanned) and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM TDB	2006/04/20 10:54
43	2022	photosensitive with (thick thickness) with (first second third)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/21 13:10
44	250	pnotosensitive with (thick thickness) with (first second third) and pivel adi (electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/21 13:10
45	248	photosensitive with (thick thickness) with (first second third) and pivel adi (electrode	IB: P() • (1 P() •	2006/04/21 13:15

	Hits	Search Text	DBs	Time Stamp
46	93	thickness) with (first second third) same (thin thinner thick thicker) and pixel adj	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/04/21 13:16